74LV165

8-bit parallel-in/serial-out shift register

Rev. 6 — 19 February 2014

Product data sheet

1. General description

The 74LV165 is an 8-bit parallel-load or serial-in shift register with complementary serial outputs (Q7 and Q7) available from the last stage. When the parallel-load input (\overline{PL}) is LOW, parallel data from the inputs D0 to D7 are loaded into the register asynchronously. When input \overline{PL} is HIGH, data enters the register serially at the input DS. It shifts one place to the right (Q0 \rightarrow Q1 \rightarrow Q2, etc.) with each positive-going clock transition. This feature allows parallel-to-serial converter expansion by tying the output Q7 to the input DS of the succeeding stage.

The clock input is a gate-OR structure which allows one input to be used as an active LOW clock enable input (CE) input. The pin assignment for the inputs CP and CE is arbitrary and can be reversed for layout convenience. The LOW-to-HIGH transition of the input CE should only take place while CP HIGH for predictable operation. Either the CP or the CE should be HIGH before the LOW-to-HIGH transition of PL to prevent shifting the data when PL is activated.

2. Features and benefits

- Wide supply voltage range from 1.0 V to 5.5 V
- Synchronous parallel-to-serial applications
- Optimized for low voltage applications: 1.0 V to 3.6 V
- Synchronous serial input for easy expansion
- Latch-up performance exceeds 250 mA
- 5.5 V tolerant inputs/outputs
- Direct interface with TTL levels (2.7 V to 3.6 V)
- Power-down mode
- Complies with JEDEC standards:
 - ◆ JESD8-5 (2.3 V to 2.7 V)
 - ◆ JESD8B/JESD36 (2.7 V to 3.6 V)
 - ◆ JESD8-1A (4.5 V to 5.5 V)
- ESD protection:
 - HBM JESD22-A114-A exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



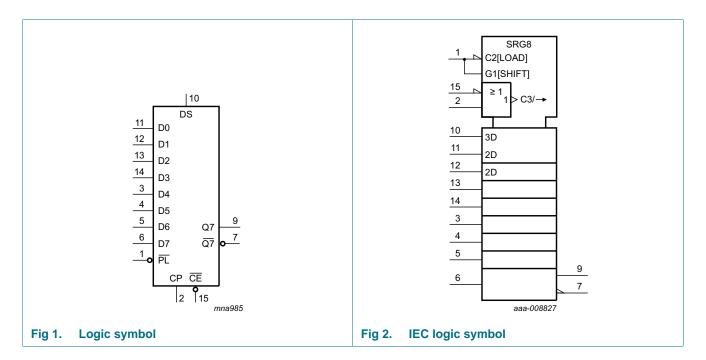
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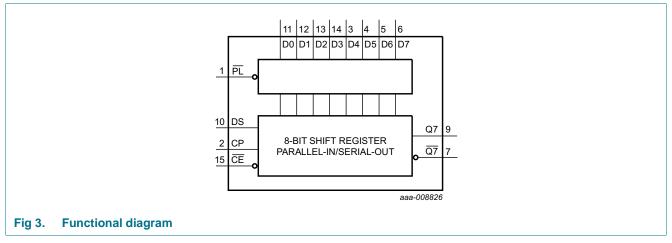
3. Ordering information

Table 1. Ordering information

Type number	Package										
	Temperature range	Name	Description	Version							
74LV165N	−40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4							
74LV165D	−40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1							
74LV165DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1							
74LV165PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1							

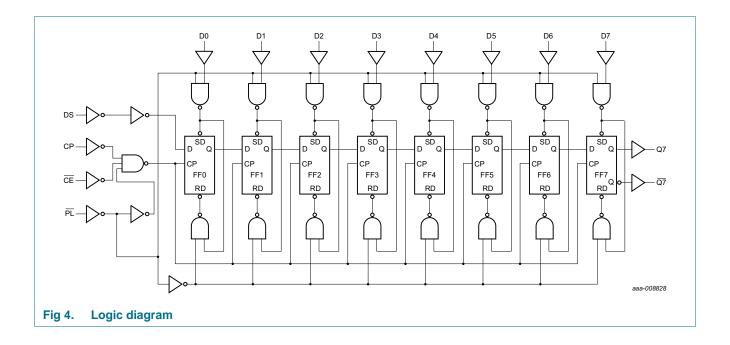
4. Functional diagram





74LV165

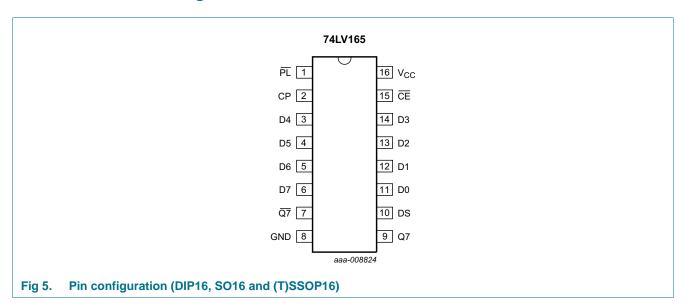
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5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

	•	
Symbol	Pin	Description
PL	1	parallel enable input (active LOW)
СР	2	clock input (LOW-to-HIGH edge-triggered)
Q7	7	complementary serial output from the last stage
GND	8	ground (0 V)
Q7	9	serial output from the last stage
DS	10	serial data input
D0 to D7	11, 12, 13, 14, 3, 4, 5, 6	parallel data inputs
CE	15	clock enable input (active LOW)
V _{CC}	16	positive supply voltage

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6. Functional description

Table 3. Function table[1]

Operating modes	Input	s				Qn regi	isters	Output	
	PL	CE	СР	DS	D0 to D7	Q0	Q1 to Q6	Q7	Q7
parallel load	L	X	X	X	L	L	L to L	L	Н
	L	Χ	Х	Х	Н	Н	H to H	Н	L
serial shift	Н	L	↑	I	Χ	L	q0 to q5	q6	q6
	Н	L	↑	h	Χ	Н	q0 to q5	q6	q6
hold "do nothing"	Н	Н	X	X	X	q0	q1 to q6	q7	q7

[1] H = HIGH voltage level;

h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

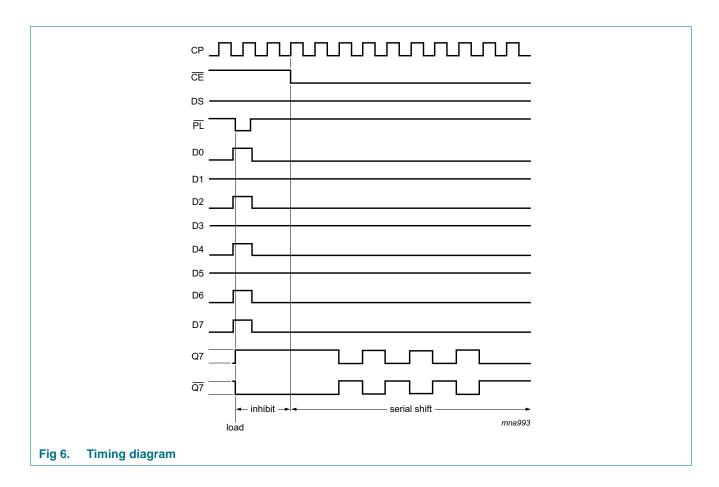
L = LOW voltage level;

I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

q = state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition;

X = don't care;

 \uparrow = LOW-to-HIGH clock transition.



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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)[1]

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	-	20	mA
VI	input voltage		-0.5	+7	V
I _{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0$	-	±50	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I _{CC}	supply current		-	+50	mA
I_{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$			
		DIP16 package	[2] -	750	mW
		SO16 package	[3] -	500	mW
		(T)SSOP16 package	<u>[4]</u> _	400	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		1.0	3.3	5.5	V
VI	input voltage		0	-	V_{CC}	V
Vo	output voltage		0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	-	+85	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.0 \text{ V to } 2.0 \text{ V}$	0	-	500	ns/V
		$V_{CC} = 2.0 \text{ V to } 2.7 \text{ V}$	0	-	200	ns/V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	0	-	100	ns/V
		$V_{CC} = 3.6 \text{ V to } 5.5 \text{ V}$	0	-	50	ns/V

^[2] Ptot derates linearly with 12 mW/K above 70 °C.

^[3] P_{tot} derates linearly with 8 mW/K above 70 °C.

^[4] P_{tot} derates linearly with 5.5 mW/K above 60 °C.

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9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	–40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
V _{IH}	HIGH-level	V _{CC} = 1.2 V	0.9	-	-	0.9	-	V
	input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.4	-	-	1.4	-	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2.0	-	-	2.0	-	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	$0.7V_{CC}$	-	-	$0.7V_{CC}$	-	V
V _{IL}	LOW-level	V _{CC} = 1.2 V	-	-	0.3	-	0.3	V
	input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	-	0.6	-	0.6	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.8	-	0.8	V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	$0.3V_{CC}$	-	$0.3V_{CC}$	
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $I_O = -100 \mu A$						
	output voltage	V _{CC} = 1.2 V	-	1.2		-		
		V _{CC} = 2.0 V	1.8	2.0	-	1.8	-	V
		$V_{CC} = 2.7 \text{ V}$	2.5	2.7	-	2.5	-	V
		V _{CC} = 3.0 V	2.8	3.0	-	2.8	-	V
		V _{CC} = 4.5 V	4.3	4.5	-	4.3	-	V
		standard outputs: $V_I = V_{IH}$ or V_{IL}						
		$V_{CC} = 3.0 \text{ V}; I_{O} = -6 \text{ mA}$	2.40	2.82	-	2.20	-	V
		$V_{CC} = 4.5 \text{ V}; I_{O} = -12 \text{ mA}$	3.60	4.20	-	3.50	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $I_O = 100 \mu A$						
	output voltage	V _{CC} = 1.2 V	-	0	-	-	-	
		V _{CC} = 2.0 V	-	0	0.2	1.8	0.2	V
		V _{CC} = 2.7 V	-	0	0.2	2.5	0.2	V
		V _{CC} = 3.0 V	-	0	0.2	2.8	0.2	V
		V _{CC} = 4.5 V	-	0	0.2	4.3	0.2	V
		standard outputs: $V_I = V_{IH}$ or V_{IL}						
		$V_{CC} = 3.0 \text{ V}; I_{O} = 6 \text{ mA}$	-	0.25	0.40	-	0.50	V
		$V_{CC} = 4.5 \text{ V}; I_{O} = 12 \text{ mA}$	-	0.35	0.55	-	0.65	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±1	-	±1	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	20	-	160	μА
ΔI_{CC}	additional supply current	$VI = V_{CC} - 0.6 V;$ $V_{CC} = 2.7 V to 3.6 V$	-	-	500	-	850	μΑ
C _I	input capacitance		-	3.5	-			pF

^[1] Typical values are measured at T_{amb} = 25 °C.

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10. Dynamic characteristics

Table 7. Dynamic characteristics

GND (ground = 0 V); for test circuit, see Figure 12

	propagation delay	$\overline{\text{CE}}$, CP to Q7, $\overline{\text{Q7}}$; see Figure 7 and Figure 8 $V_{\text{CC}} = 1.2 \text{ V}$ $V_{\text{CC}} = 2.0 \text{ V}$ $V_{\text{CC}} = 2.7 \text{ V}$ $V_{\text{CC}} = 3.0 \text{ V}$ to 3.6 V $V_{\text{CC}} = 3.3 \text{ V}$; $C_{\text{L}} = 15 \text{ pF}$ $V_{\text{CC}} = 4.5 \text{ V}$ to 5.5 V $\overline{\text{PL}}$ to Q7, $\overline{\text{Q7}}$; see Figure 8	[2]	- - - -	115 38 27 22	- 61 43 36	Min - - -	- 76 54	ns ns ns
		see Figure 7 and Figure 8 $V_{CC} = 1.2 \text{ V}$ $V_{CC} = 2.0 \text{ V}$ $V_{CC} = 2.7 \text{ V}$ $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 3.3 \text{ V; } C_L = 15 \text{ pF}$ $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	[3]		38 27 22	61 43	-	76 54	ns
		$V_{CC} = 2.0 \text{ V}$ $V_{CC} = 2.7 \text{ V}$ $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 3.3 \text{ V; } C_L = 15 \text{ pF}$ $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$			38 27 22	61 43	-	76 54	ns
		$V_{CC} = 2.7 \text{ V}$ $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 3.3 \text{ V; } C_L = 15 \text{ pF}$ $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-	27 22	43	-	54	
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 3.3 \text{ V}; C_L = 15 \text{ pF}$ $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-	22				ns
		$V_{CC} = 3.3 \text{ V}; C_L = 15 \text{ pF}$ $V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$				36			
		V _{CC} = 4.5 V to 5.5 V	<u>[4]</u>	-		50	-	45	ns
			[4]		18	-	-	-	ns
		PL to Q7, Q7; see Figure 8		-	15	24	-	30	ns
		V _{CC} = 1.2 V		-	110	-	-	-	ns
		$V_{CC} = 2.0 \text{ V}$		-	35	56	-	70	ns
		V _{CC} = 2.7 V		-	24	39	-	49	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	-	20	33	-	41	ns
		$V_{CC} = 3.3 \text{ V}; C_L = 15 \text{ pF}$		-	18	-	-	-	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	[4]	-	14	22	-	27	ns
		D7 to Q7, $\overline{Q7}$; CL = 15 pF; see Figure 9							
		V _{CC} = 1.2 V		-	90	-	-	-	ns
		V _{CC} = 2.0 V		-	28	45	-	56	ns
		V _{CC} = 2.7 V		-	20	32	-	40	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	-	17	27	-	33	ns
		$V_{CC} = 3.3 \text{ V}; C_L = 15 \text{ pF}$		-	14	-	-	-	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	<u>[4]</u>	-	11	18	-	22	ns
t _W	pulse width	CP input HIGH to LOW; see Figure 7							
		$V_{CC} = 2.0 \text{ V}$		34	10	-	41	-	ns
		$V_{CC} = 2.7 \text{ V}$		25	8	-	30	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	20	7	-	24	-	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	<u>[4]</u>	15	5	-	18	-	ns
		PL input LOW; see Figure 8							
		$V_{CC} = 2.0 \text{ V}$		34	10	-	41	-	ns
		$V_{CC} = 2.7 \text{ V}$		25	8	-	30	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	20	7	-	24	-	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	[4]	15	5	-	18	-	ns

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Table 7. Dynamic characteristics ...continued GND (ground = 0 V); for test circuit, see <u>Figure 12</u>

Symbol	Parameter	Conditions		-40	°C to +8	5 °C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max		
t _{rec}	recovery time	PL to CP, CE; see Figure 8	'		'	•			'
		V _{CC} = 1.2 V		-	40	-	-	-	ns
		$V_{CC} = 2.0 \text{ V}$		24	15	-	30	-	ns
		$V_{CC} = 2.7 \text{ V}$		18	11	-	23	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	17	10	-	21	-	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	<u>[4]</u>	12	7	-	15	-	ns
·su	set-up time	DS to CP, CE; see Figure 10							
		$V_{CC} = 1.2 \text{ V}$		-	-8	-	-	-	ns
		$V_{CC} = 2.0 \text{ V}$		22	-2	-	26	-	ns
		$V_{CC} = 2.7 V$		16	-1	-	19	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	13	-1	-	15	-	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	<u>[4]</u>	9	0	-	10	-	ns
		CE to CP, CP to CE; see Figure 10							
		V _{CC} = 1.2 V		-	20	-	-	-	ns
		V _{CC} = 2.0 V		22	7	-	26	-	ns
		V _{CC} = 2.7 V		16	5	-	19	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	13	4	-	15	-	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	<u>[4]</u>	9	3	-	10	-	ns
		Dn to PL; see Figure 11							
		V _{CC} = 1.2 V		-	25	-	-	-	ns
		V _{CC} = 2.0 V		22	8	-	26	-	ns
		$V_{CC} = 2.7 \text{ V}$		16	6	-	19	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	13	5	-	15	-	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	[4]	9	4	-	10	-	ns
h	hold time	DS to CP, CE; Dn to PL; see Figure 10 and Figure 11							
		V _{CC} = 1.2 V		-	20	-	-	-	ns
		V _{CC} = 2.0 V		22	7	-	26	-	ns
		V _{CC} = 2.7 V		16	5	-	19	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	13	4	-	15	-	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	<u>[4]</u>	9	3	-	10	-	ns
		CE to CP, CP to CE; see Figure 10							
		V _{CC} = 1.2 V		-	-30	-	-	-	ns
		V _{CC} = 2.0 V		5	-8	-	5	-	ns
		V _{CC} = 2.7 V		5	-6	-	5	-	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	5	-5	-	5	-	ns
		V _{CC} = 4.5 V to 5.5 V	<u>[4]</u>	5	-4	-	5	-	ns

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Table 7. Dynamic characteristics ...continued GND (ground = 0 V); for test circuit, see Figure 12

Symbol	Parameter	Conditions		-40	°C to +8	5 °C	–40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max		
f_{max}	maximum	see Figure 7							
	frequency	V _{CC} = 2.0 V		14	40	-	12	-	MHz
		$V_{CC} = 2.7 V$		19	60	-	16	-	MHz
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	[3]	24	65	-	20	-	MHz
		$V_{CC} = 3.3 \text{ V}; C_L = 15 \text{ pF}$		-	78	-	-	-	MHz
		V _{CC} = 4.5 V to 5.5 V	<u>[4]</u>	36	75	-	30	-	MHz
C _{PD}	power dissipation capacitance	$V_I = GND$ to V_{CC} ; $V_{CC} = 3.3 \text{ V}$	<u>[5]</u>	-	35	-			pF

- [1] Typical values are measured at $T_{amb} = 25$ °C.
- [2] t_{pd} is the same as t_{PHL} and t_{PLH} .
- [3] Typical values are measured at V_{CC} = 3.3 V.
- [4] Typical values are measured at $V_{CC} = 5.0 \text{ V}$.
- [5] C_{PD} is used to determine the dynamic power dissipation $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma \ (C_L \times V_{CC}^2 \times f_o) \ (P_D \ in \ \mu W)$, where:

 f_i = input frequency in MHz;

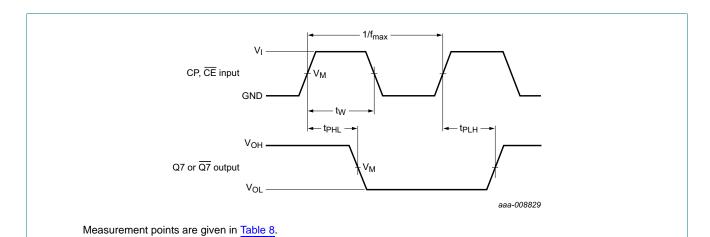
f_o = output frequency in MHz;

 $\Sigma (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs};$

C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V.

11. Waveforms



The changing to output assumes that internal Q6 is opposite state from Q7.

Fig 7. Clock pulse (CP) and clock enable (CE) to output (Q7 or Q7) propagation delays, clock pulse width and maximum clock frequency

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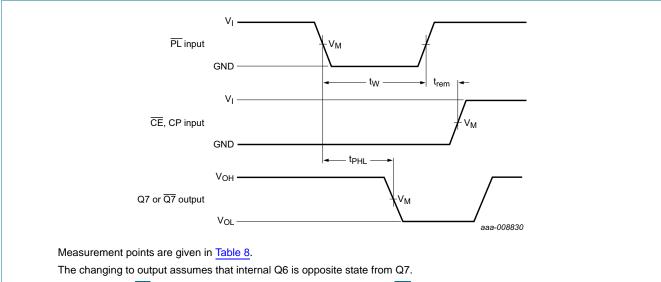
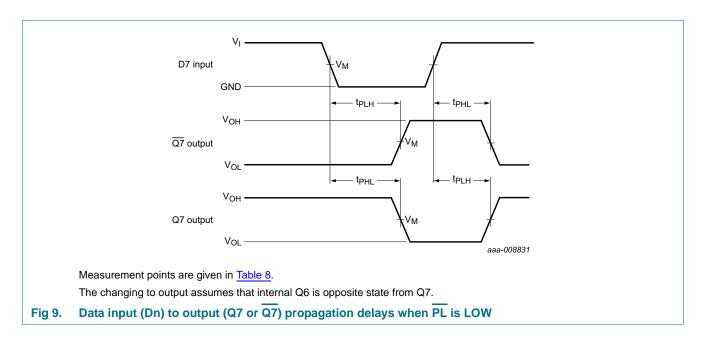
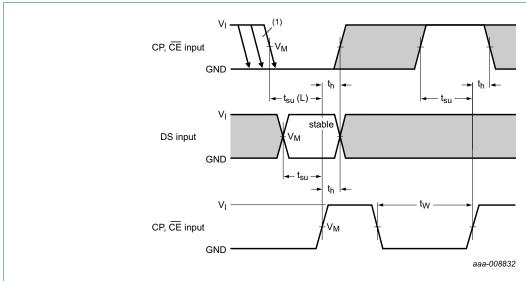


Fig 8. Parallel load (PL) pulse width, parallel load to output (Q7 or Q7) propagation delays, parallel load to clock (CP) and clock enable (CE) recovery time



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Measurement points are given in Table 8.

(1) CE may change only from HIGH-to-LOW while CP is LOW. The shaded areas indicate when the input is permitted to change for predictable output performance.

Fig 10. Set-up and hold times

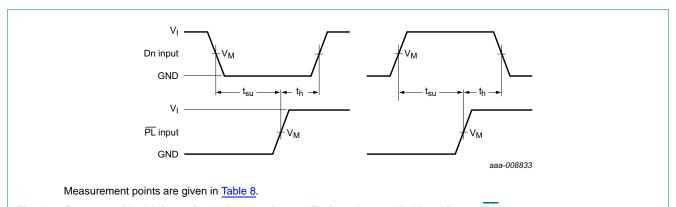
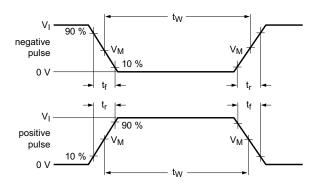


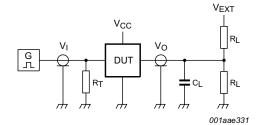
Fig 11. Set-up and hold times from the data inputs (Dn) to the parallel load input (PL)

Table 8. Measurement points

Supply voltage	Input	Output
V _{CC}	V _M	V _M
< 2.7 V	0.5V _{CC}	0.5V _{CC}
2.7 V to 3.6 V	1.5 V	1.5 V
≥ 4.5 V	0.5V _{CC}	0.5V _{CC}

8-bit parallel-in/serial-out shift register





Test data is given in Table 9.

Definitions for test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 12. Test circuit for measuring switching times

Table 9. Test data

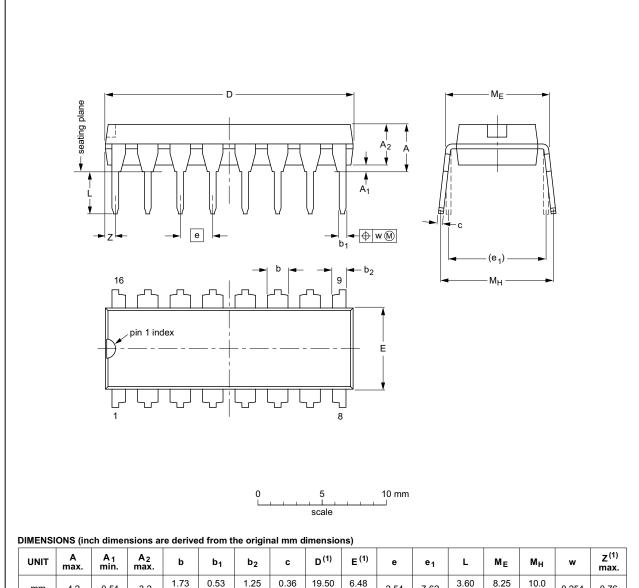
Supply voltage	Input		Load	Load				
	VI	t _r , t _f	C _L	R_L	t _{PHL} , t _{PLH}			
< 2.7 V	V _{CC}	2.5 ns	50 pF	1 kΩ	open			
2.7 V to 3.6 V	2.7 V	2.5 ns	50 pF, 15 pF	1 kΩ	open			
≥ 4.5 V	V _{CC}	2.5 ns	50 pF	1 kΩ	open			

8-bit parallel-in/serial-out shift register

12. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

VERSION IEC JEDEC JEITA PROJECTION 95-01-14	OUTLINE		REFER	EUROPEAN	ISSUE DATE		
1 SO138-4	VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
03-02-13	SOT38-4						95-01-14 03-02-13

Fig 13. Package outline SOT38-4 (DIP16)

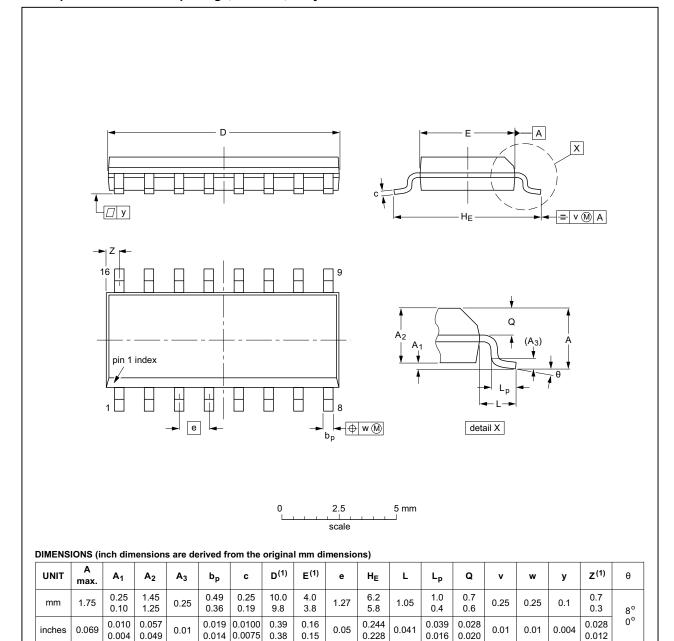
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8-bit parallel-in/serial-out shift register

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012			99-12-27 03-02-19
				, , , , , , , , , , , , , , , , , , ,	

Fig 14. Package outline SOT109-1 (SO16)

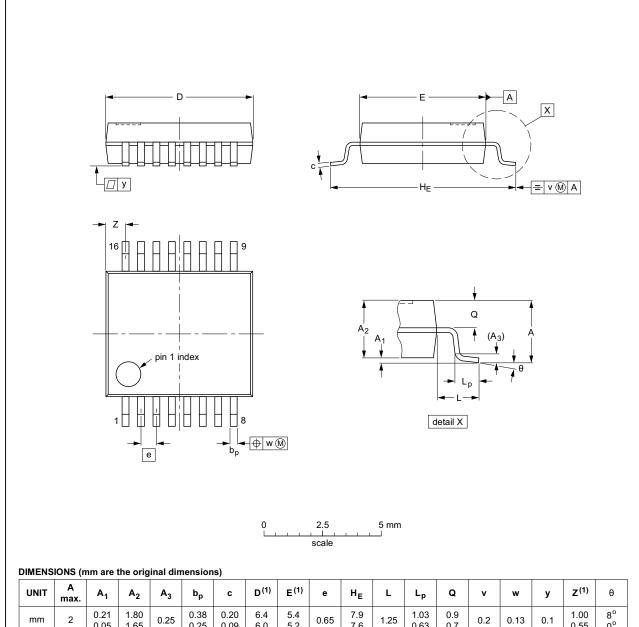
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74LV165 **NXP Semiconductors**

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNI	Γ A max	A ₁	A ₂	A ₃	b _p	C	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT338-1		MO-150			99-12-27 03-02-19

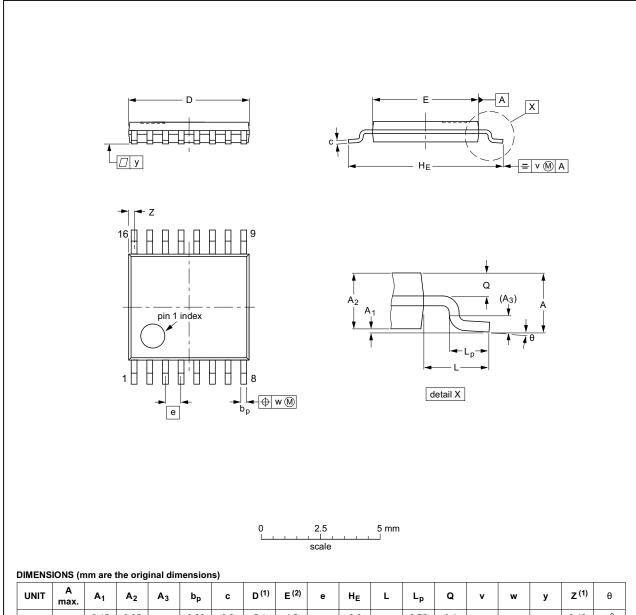
Fig 15. Package outline SOT338-1 (SSOP16)

74LV165 **NXP Semiconductors**

8-bit parallel-in/serial-out shift register

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A ₁	A ₂	A ₃	b _p	С	D ⁽¹⁾	E (2)	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ	
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°	

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT403-1		MO-153				-99-12-27 03-02-18	

Fig 16. Package outline SOT403-1 (TSSOP16)

Product data sheet

8-bit parallel-in/serial-out shift register

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
74LV165 v.6	20140219	Product data sheet	-	74LV165 v.5				
Modifications:	 Typo correct 	ted in Table 2 "Pin descript	ion <u>"</u>					
74LV165 v.5	20130909	Product data sheet	-	74LV165 v.4				
Modifications:	 Typo correct 	ted in the header of Table (6 "Static characteristics"					
74LV165 v.4	20130830	Product data sheet	-	74LV165_CNV_3				
Modifications:		of this data sheet has been of NXP Semiconductors.	redesigned to comply w	vith the new identity				
	 Legal texts have been adapted to the new company name where appropriate. 							
	 Family data 	added, see Section 9 "State	tic characteristics"					
74LV165_CNV_3	December 1998	Product specification	-	-				

8-bit parallel-in/serial-out shift register

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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